



PATENT 81880.0087

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Hiroyuki KINOSHITA et al.

Serial No: 08/808,315

Filed: February 28, 1997

For: SAPPHIRE SINGLE CRYSTAL.

SEMICONDUCTOR LASER DIODE

USING THE SAME FOR

SUBSTRATE, AND METHOD FOR MANUFACTURING THE SAME (As

Amended)

Art Unit: 2881

Examiner: James Menefee

> I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed

Commissioner for Patents Washington D.C. 20231, on

October 24, 2001 **Date of Deposit**

Diane Zynn Name

10/24/01 Signature Date

PETITION FOR EXTENSION OF TIME

Box RCE Commissioner for Patents Washington, D.C. 20231

Dear Sir:

In accordance with 37 C.F.R. 1.136, Applicant respectfully petitions the Commissioner for a three-month extension of time extending to October 24, 2001, the period for response to the Final Office Action dated April 24, 2001. A check for \$810 (\$920 less \$110 previously paid) is enclosed. The responsive paper(s) are attached.

Please charge any insufficiency or credit any overpayment to Deposit Account No. 50-1314. A copy of this petition is enclosed.

02/28/2002 MGEBREM1 00000021 08808315

02 FC:117

810.00 OP

Date: October 24, 2001

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Respectfully submitted.

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